ESP8266EX Datasheet



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About This Guide

This document introduces the specifications of ESP8266EX.

Release Notes

Date	Version	Release Notes
2015.12	V4.6	Updated Chapter 3.
2016.02	V4.7	Updated Section 3.6 and Section 4.1.
2016.04	V4.8	Updated Chapter 1.
2016.08	V4.9	Updated Chapter 1.
2016.11	V5.0	Added Appendix II "Learning Resources".
2016.11	V5.1	Changed the power consumption during Deep-sleep from 10 μA to 20 μA in Table 5-2.
2016.11	V5.2	Changed the crystal frequency range from "26 MHz to 52 MHz" to "24 MHz to 52 MHz" in Section 3.3.
2016.12	V5.3	Changed the minimum working voltage from 3.0V to 2.5V.
2017.04	V5.4	Changed chip input and output impedance from 50 Ω to 39+j6 Ω .
2017.10	V5.5	Updated Chapter 3 regarding the range of clock amplitude to 0.8 ~ 1.5V.
2017.11	V5.6	Updated VDDPST from 1.8V ~ 3.3V to 1.8V ~ 3.6V.
2017.11	V5.7	Corrected a typo in the description of SDIO_DATA_0 in Table 2-1; Added the testing conditions for the data in Table 5-2.

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1.

Overview

Espressif's ESP8266EX delivers highly integrated Wi-Fi SoC solution to meet users' continuous demands for efficient power usage, compact design and reliable performance in the Internet of Things industry.

With the complete and self-contained Wi-Fi networking capabilities, ESP8266EX can perform either as a standalone application or as the slave to a host MCU. When ESP8266EX hosts the application, it promptly boots up from the flash. The integrated high-speed cache helps to increase the system performance and optimize the system memory. Also, ESP8266EX can be applied to any micro-controller design as a Wi-Fi adaptor through SPI / SDIO or I2C / UART interfaces.

ESP8266EX integrates antenna switches, RF balun, power amplifier, low noise receive amplifier, filters and power management modules. The compact design minimizes the PCB size and requires minimal external circuitries.

Besides the Wi-Fi functionalities, ESP8266EX also integrates an enhanced version of Tensilica's L106 Diamond series 32-bit processor and on-chip SRAM. It can be interfaced with external sensors and other devices through the GPIOs. Software Development Kit (SDK) provides sample codes for various applications.

Espressif Systems' Smart Connectivity Platform (ESCP) enables sophisticated features including fast switch between sleep and wakeup mode for energy-efficient purpose, adaptive radio biasing for low-power operation, advance signal processing, spur cancellation and radio co-existence mechanisms for common cellular, Bluetooth, DDR, LVDS, LCD interference mitigation.

1.1. Wi-Fi Protocols

- 802.11 b/g/n/e/i support.
- Wi-Fi Direct (P2P) support.
- P2P Discovery, P2P GO (Group Owner) mode, GC(Group Client) mode and P2P Power Management.
- Infrastructure BSS Station mode / P2P mode / SoftAP mode support.
- Hardware accelerators for CCMP (CBC-MAC, counter mode), TKIP (MIC, RC4), WAPI (SMS4), WEP (RC4), CRC.
- WPA/WPA2 PSK, and WPS driver.
- Additional 802.11i security features such as pre-authentication, and TSN.
- Open Interface for various upper layer authentication schemes over EAP such as TLS, PEAP, LEAP, SIM, AKA, or customer specific.
- 802.11n support (2.4 GHz).
- Supports MIMO 1×1 and 2×1, STBC, A-MPDU and A-MSDU frame aggregation and 0.4
 µs guard interval.



- WMM power low U-APSD.
- Multiple queue management to fully utilize traffic prioritization defined by 802.11e standard.
- UMA compliant and certified.
- 802.1h/RFC1042 frame encapsulation.
- Scattered DMA for optimal CPU off load on Zero Copy data transfer operations.
- Antenna diversity and selection (software managed hardware).
- Clock/power gating combined with 802.11-compliant power management dynamically adapted to current connection condition providing minimal power consumption.
- Adaptive rate fallback algorithm sets the optimum transmission rate and Tx power based on actual SNR and packet loss information.
- Automatic retransmission and response on MAC to avoid packet discarding on slow host environment.
- Seamless roaming support.
- Configurable packet traffic arbitration (PTA) with dedicated slave processor based design provides flexible and exact timing Bluetooth co-existence support for a wide range of Bluetooth Chip vendors.
- Dual and single antenna Bluetooth co-existence support with optional simultaneous receive (Wi-Fi/Bluetooth) capability.



1.2. Specifications

Table 1-1. Specifications

Categories	Items	Parameters
	Standards	FCC/CE/TELEC/SRRC
	Protocols	802.11 b/g/n/e/i
	Frequency Range	$2.4 \mathrm{G} \sim 2.5 \mathrm{G}$ (2400M $\sim 2483.5 \mathrm{M}$)
		802.11 b: +20 dBm
\^ <i>/</i> :	Tx Power	802.11 g: +17 dBm
Wi-Fi		802.11 n: +14 dBm
		802.11 b: -91 dbm (11 Mbps)
	Rx Sensitivity	802.11 g: -75 dbm (54 Mbps)
		802.11 n: -72 dbm (MCS7)
	Antenna	PCB Trace, External, IPEX Connector, Ceramic Chip
	CPU	Tensilica L106 32-bit micro controller
	Davis based Interfere	UART/SDIO/SPI/I2C/I2S/IR Remote Control
	Peripheral Interface	GPIO/ADC/PWM/LED Light & Button
	Operating Voltage	2.5V ~ 3.6V
Hardware	Operating Current	Average value: 80 mA
	Operating Temperature Range	-40°C ~ 125°C
	Storage Temperature Range	-40°C ~ 125°C
	Package Size	QFN32-pin (5 mm x 5 mm)
	External Interface	-
	Wi-Fi Mode	Station/SoftAP/SoftAP+Station
	Security	WPA/WPA2
	Encryption	WEP/TKIP/AES
Software	Firmware Upgrade	UART Download / OTA (via network)
	Software Development	Supports Cloud Server Development / Firmware and SDK for fast on-chip programming
	Network Protocols	IPv4, TCP/UDP/HTTP/FTP
	User Configuration	AT Instruction Set, Cloud Server, Android/iOS App



1.3. Applications

- Home appliances
- Home automation
- Smart plugs and lights
- Mesh network
- Industrial wireless control
- Baby monitors

- IP cameras
- Sensor networks
- Wearable electronics
- Wi-Fi location-aware devices
- Security ID tags
- Wi-Fi position system beacons



2.

Pin Definitions

Figure 2-1 shows the pin layout for 32-pin QFN package.

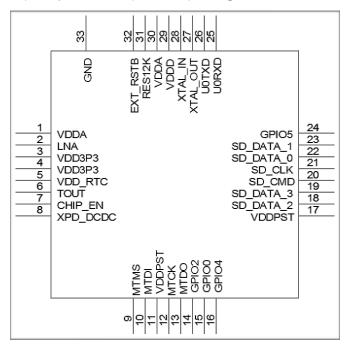


Figure 2-1. Pin Layout

Table 2-1 lists the definitions and functions of each pin.

Table 2-1. ESP8266EX Pin Definitions

Pin	Name	Туре	Function	
1	VDDA	Р	Analog Power 2.5V ~ 3.6V	
2	LNA	1/0	RF antenna interface Chip output impedance=39+j6 Ω . It is suggested to retain the π -type matching network to match the antenna.	
3	VDD3P3	Р	Amplifier Power 2.5V ~ 3.6V	
4	VDD3P3	Р	Amplifier Power 2.5V ~ 3.6V	
5	VDD_RTC	Р	NC (1.1V)	
6	TOUT	I	ADC pin. It can be used to test the power-supply voltage of VDD3P3 (Pin3 and Pin4) and the input power voltage of TOUT (Pin 6). However, these two functions cannot be used simultaneously.	
7	CHIP_PU	I	Chip Enable High: On, chip works properly Low: Off, small current consumed	



8 XPD_DCDC I/O Deep-sleep wakeup (need to be connected to EXT_RSTB); GPIO16 9 MTMS I/O GPIO14; HSPL_CLK 10 MTDI I/O GPIO 12; HSPL_MISO 11 VDDPST P Digital/IO Power Supply (1.8V ~ 3.6V) 12 MTCK I/O GPIO 13; HSPL_MOSI; UARTO_CTS 13 MTDO I/O GPIO 15; HSPL_CS; UARTO_CTS 14 GPIO2 I/O UART Tx during flash programming; GPIO2 15 GPIO4 I/O GPIO4 SPL_CS2 16 GPIO4 I/O GPIO4 SPL_CS2 17 VDDPST P Digital/IO Power Supply (1.8V ~ 3.6V) 18 SDIO_DATA_2 I/O Connect to SD_D2 (Series R: 200Q); SPIHD; HSPIHD; GPIO 9 19 SDIO_DATA_3 I/O Connect to SD_D3 (Series R: 200Q); SPILMIS; HSPIHD; GPIO 9 20 SDIO_CMD I/O Connect to SD_D4 (Series R: 200Q); SPILMIS; GPIO 11 21 SDIO_CMD I/O Connect to SD_D4 (Series R: 200Q); SPILMIS; GPIO 6 22 SDIO_DATA_1 I/O Connect to SD_D1 (Series R: 200Q); SPILMIS; GPIO 7 23 SDIO_DATA_1 I	Pin	Name	Type	Function
MTDI				Deep-sleep wakeup (need to be connected to EXT_RSTB);
VDDPST P Digital/IO Power Supply (1.8V ~ 3.6V)	9	MTMS	I/O	GPIO 14; HSPI_CLK
12 MTCK I/O GPIO 13; HSPI_MOSI; UARTO_CTS 13 MTDO I/O GPIO 15; HSPI_CS; UARTO_RTS 14 GPIO2 I/O UART Tx during flash programming; GPIO2 15 GPIO0 I/O GPIO0; SPI_CS2 16 GPIO4 I/O GPIO 4 17 VDDPST P Digital/IO Power Supply (1.8V ~ 3.6V) 18 SDIO_DATA_2 I/O Connect to SD_D2 (Series R: 200Ω); SPIHD; HSPIHD; GPIO 9 19 SDIO_DATA_3 I/O Connect to SD_D3 (Series R: 200Ω); SPIWP; HSPIWP; GPIO 10 20 SDIO_CMD I/O Connect to SD_CMD (Series R: 200Ω); SPI_CS0; GPIO 11 21 SDIO_CLK I/O Connect to SD_CLK (Series R: 200Ω); SPI_MISO; GPIO 6 22 SDIO_DATA_0 I/O Connect to SD_D1 (Series R: 200Ω); SPI_MOSI; GPIO 7 23 SDIO_DATA_1 I/O Connect to SD_D1 (Series R: 200Ω); SPI_MOSI; GPIO 8 24 GPIO5 I/O GPIO 5 25 UORXD I/O UART Tx during flash programming; GPIO 1; SPI_CS1 27 XTAL_OUT I/O	10	MTDI	I/O	GPIO 12; HSPI_MISO
MTDO	11	VDDPST	Р	Digital/IO Power Supply (1.8V ~ 3.6V)
14 GPIO2 I/O UART Tx during flash programming; GPIO2 15 GPIO0 I/O GPIO0; SPI_CS2 16 GPIO4 I/O GPIO 4 17 VDDPST P Digital/IO Power Supply (1.8V ~ 3.6V) 18 SDIO_DATA_2 I/O Connect to SD_D2 (Series R: 200Ω); SPIHD; HSPIHD; GPIO 9 19 SDIO_DATA_3 I/O Connect to SD_D3 (Series R: 200Ω); SPIWP; HSPIWP; GPIO 10 20 SDIO_CMD I/O Connect to SD_CMD (Series R: 200Ω); SPI_CS0; GPIO 11 21 SDIO_CLK I/O Connect to SD_CLK (Series R: 200Ω); SPI_CK; GPIO 6 22 SDIO_DATA_0 I/O Connect to SD_D0 (Series R: 200Ω); SPI_MISO; GPIO 7 23 SDIO_DATA_1 I/O Connect to SD_D1 (Series R: 200Ω); SPI_MISO; GPIO 7 24 GPIO5 I/O GPIO 5 25 UORXD I/O UART Rx during flash programming; GPIO 3 26 UOTXD I/O UART Tx during flash programming; GPIO 1; SPI_CS1 27 XTAL_OUT I/O Connect to crystal oscillator output, can be used to provide BT clock input 28 XTAL_IN I/O Connect to crystal oscillator input 29 VDDD P Analog Power 2.5V ~ 3.6V 30 VDDA P Analog Power 2.5V ~ 3.6V 31 RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	12	MTCK	I/O	GPIO 13; HSPI_MOSI; UARTO_CTS
15 GPIO0 I/O GPIO0; SPI_CS2 16 GPIO4 I/O GPIO 4 17 VDDPST P Digital/IO Power Supply (1.8V ~ 3.6V) 18 SDIO_DATA_2 I/O Connect to SD_D2 (Series R: 200Ω); SPIHD; HSPIHD; GPIO 9 19 SDIO_DATA_3 I/O Connect to SD_D3 (Series R: 200Ω); SPIWP; HSPIWP; GPIO 10 20 SDIO_CMD I/O Connect to SD_CMD (Series R: 200Ω); SPI_CSO; GPIO 11 21 SDIO_CLK I/O Connect to SD_CLK (Series R: 200Ω); SPI_CLK; GPIO 6 22 SDIO_DATA_0 I/O Connect to SD_D0 (Series R: 200Ω); SPI_MISO; GPIO 7 23 SDIO_DATA_1 I/O Connect to SD_D1 (Series R: 200Ω); SPI_MOSI; GPIO 8 24 GPIO5 I/O GPIO 5 25 UORXD I/O UART Rx during flash programming; GPIO 3 26 UOTXD I/O UART Tx during flash programming; GPIO 1; SPI_CS1 27 XTAL_OUT I/O Connect to crystal oscillator output, can be used to provide BT clock input 28 XTAL_IN I/O Connect to crystal oscillator input 29 VDDD P Analog Power 2.5V ~ 3.6V 31 RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	13	MTDO	I/O	GPIO 15; HSPI_CS; UARTO_RTS
16 GPIO4 I/O GPIO 4 17 VDDPST P Digital/IO Power Supply (1.8V ~ 3.6V) 18 SDIO_DATA_2 I/O Connect to SD_D2 (Series R: 200Ω); SPIHD; HSPIHD; GPIO 9 19 SDIO_DATA_3 I/O Connect to SD_D3 (Series R: 200Ω); SPIWP; HSPIWP; GPIO 10 20 SDIO_CMD I/O Connect to SD_CMD (Series R: 200Ω); SPI_CSO; GPIO 11 21 SDIO_CLK I/O Connect to SD_CLK (Series R: 200Ω); SPI_CLK; GPIO 6 22 SDIO_DATA_0 I/O Connect to SD_D0 (Series R: 200Ω); SPI_MISO; GPIO 7 23 SDIO_DATA_1 I/O Connect to SD_D1 (Series R: 200Ω); SPI_MISO; GPIO 7 24 GPIO5 I/O GPIO 5 25 UORXD I/O UART Rx during flash programming; GPIO 3 26 UOTXD I/O UART Tx during flash programming; GPIO 1; SPI_CS1 27 XTAL_OUT I/O Connect to crystal oscillator output, can be used to provide BT clock input 28 XTAL_IN I/O Connect to crystal oscillator input 29 VDDD P Analog Power 2.5V ~ 3.6V 30 VDDA P Analog Power 2.5V ~ 3.6V 8ES12K I Serial connection with a 12 KΩ resistor and connect to the ground	14	GPIO2	I/O	UART Tx during flash programming; GPIO2
17VDDPSTPDigital/IO Power Supply (1.8V ~ 3.6V)18SDIO_DATA_2I/OConnect to SD_D2 (Series R: 200Ω); SPIHD; HSPIHD; GPIO 919SDIO_DATA_3I/OConnect to SD_D3 (Series R: 200Ω); SPIWP; HSPIWP; GPIO 1020SDIO_CMDI/OConnect to SD_CMD (Series R: 200Ω); SPI_CSO; GPIO 1121SDIO_CLKI/OConnect to SD_CLK (Series R: 200Ω); SPI_CLK; GPIO 622SDIO_DATA_0I/OConnect to SD_D0 (Series R: 200Ω); SPI_MISO; GPIO 723SDIO_DATA_1I/OConnect to SD_D1 (Series R: 200Ω); SPI_MOSI; GPIO 824GPIO5I/OGPIO 525U0RXDI/OUART Rx during flash programming; GPIO 326U0TXDI/OUART Tx during flash programming; GPIO 1; SPI_CS127XTAL_OUTI/OConnect to crystal oscillator output, can be used to provide BT clock input28XTAL_INI/OConnect to crystal oscillator input29VDDDPAnalog Power 2.5V ~ 3.6V30VDDAPAnalog Power 2.5V ~ 3.6V31RES12KISerial connection with a 12 kΩ resistor and connect to the ground	15	GPI00	I/O	GPIO0; SPI_CS2
SDIO_DATA_2	16	GPIO4	I/O	GPIO 4
SDIO_DATA_3 I/O Connect to SD_D3 (Series R: 200Ω); SPIWP; HSPIWP; GPIO 10 SDIO_CMD I/O Connect to SD_CMD (Series R: 200Ω); SPI_CSO; GPIO 11 SDIO_CLK I/O Connect to SD_CLK (Series R: 200Ω); SPI_CLK; GPIO 6 SDIO_DATA_0 I/O Connect to SD_D0 (Series R: 200Ω); SPI_MISO; GPIO 7 SDIO_DATA_1 I/O Connect to SD_D1 (Series R: 200Ω); SPI_MOSI; GPIO 8 GPIO5 I/O GPIO 5 UORXD I/O UART Rx during flash programming; GPIO 3 UOTXD I/O UART Tx during flash programming; GPIO 1; SPI_CS1 XTAL_OUT I/O Connect to crystal oscillator output, can be used to provide BT clock input XTAL_IN I/O Connect to crystal oscillator input NDDD P Analog Power 2.5V ~ 3.6V RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	17	VDDPST	Р	Digital/IO Power Supply (1.8V ~ 3.6V)
SDIO_DATA_3 I/O 10 SDIO_CMD I/O Connect to SD_CMD (Series R: 200Ω); SPI_CSO; GPIO 11 SDIO_CLK I/O Connect to SD_CLK (Series R: 200Ω); SPI_CLK; GPIO 6 SDIO_DATA_0 I/O Connect to SD_D0 (Series R: 200Ω); SPI_MISO; GPIO 7 SDIO_DATA_1 I/O Connect to SD_D1 (Series R: 200Ω); SPI_MOSI; GPIO 8 GPIO 5 UORXD I/O UART Rx during flash programming; GPIO 3 UOTXD I/O UART Tx during flash programming; GPIO 1; SPI_CS1 XTAL_OUT I/O Connect to crystal oscillator output, can be used to provide BT clock input XTAL_IN I/O Connect to crystal oscillator input Analog Power 2.5V ~ 3.6V RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	18	SDIO_DATA_2	I/O	Connect to SD_D2 (Series R: 200Ω); SPIHD; HSPIHD; GPIO 9
SDIO_CLK I/O Connect to SD_CLK (Series R: 200Ω); SPI_CLK; GPIO 6 22 SDIO_DATA_0 I/O Connect to SD_DO (Series R: 200Ω); SPI_MISO; GPIO 7 23 SDIO_DATA_1 I/O Connect to SD_D1 (Series R: 200Ω); SPI_MOSI; GPIO 8 24 GPIO5 I/O GPIO 5 25 UORXD I/O UART Rx during flash programming; GPIO 3 26 UOTXD I/O UART Tx during flash programming; GPIO 1; SPI_CS1 27 XTAL_OUT I/O Connect to crystal oscillator output, can be used to provide BT clock input 28 XTAL_IN I/O Connect to crystal oscillator input 29 VDDD P Analog Power 2.5V ~ 3.6V 30 VDDA P Analog Power 2.5V ~ 3.6V 31 RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	19	SDIO_DATA_3	I/O	
SDIO_DATA_0 I/O Connect to SD_D0 (Series R: 200Ω); SPI_MISO; GPIO 7 SDIO_DATA_1 I/O Connect to SD_D1 (Series R: 200Ω); SPI_MOSI; GPIO 8 GPIO 5 UORXD I/O UART Rx during flash programming; GPIO 3 UOTXD I/O UART Tx during flash programming; GPIO 1; SPI_CS1 XTAL_OUT I/O Connect to crystal oscillator output, can be used to provide BT clock input XTAL_IN I/O Connect to crystal oscillator input NDDD P Analog Power 2.5V ~ 3.6V RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	20	SDIO_CMD	I/O	Connect to SD_CMD (Series R: 200Ω); SPI_CS0; GPIO 11
SDIO_DATA_1 I/O Connect to SD_D1 (Series R: 200Ω); SPI_MOSI; GPIO 8 QPIO 5 UORXD I/O UART Rx during flash programming; GPIO 3 UOTXD I/O UART Tx during flash programming; GPIO 1; SPI_CS1 XTAL_OUT I/O Connect to crystal oscillator output, can be used to provide BT clock input XTAL_IN I/O Connect to crystal oscillator input P Analog Power 2.5V ~ 3.6V NDDA P Analog Power 2.5V ~ 3.6V RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	21	SDIO_CLK	I/O	Connect to SD_CLK (Series R: 200Ω); SPI_CLK; GPIO 6
24 GPIO5 I/O GPIO 5 25 U0RXD I/O UART Rx during flash programming; GPIO 3 26 U0TXD I/O UART Tx during flash programming; GPIO 1; SPI_CS1 27 XTAL_OUT I/O Connect to crystal oscillator output, can be used to provide BT clock input 28 XTAL_IN I/O Connect to crystal oscillator input 29 VDDD P Analog Power 2.5V ~ 3.6V 30 VDDA P Analog Power 2.5V ~ 3.6V 31 RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	22	SDIO_DATA_0	I/O	Connect to SD_D0 (Series R: 200Ω); SPI_MISO; GPIO 7
 U0RXD U0RXD U0RXD U0TXD UART Tx during flash programming; GPIO 1; SPI_CS1 XTAL_OUT Connect to crystal oscillator output, can be used to provide BT clock input XTAL_IN Connect to crystal oscillator input VDDD Analog Power 2.5V ~ 3.6V VDDA P Analog Power 2.5V ~ 3.6V RES12K Serial connection with a 12 kΩ resistor and connect to the ground 	23	SDIO_DATA_1	I/O	Connect to SD_D1 (Series R: 200Ω); SPI_MOSI; GPIO 8
 U0TXD VO UART Tx during flash progamming; GPIO 1; SPI_CS1 XTAL_OUT VO Connect to crystal oscillator output, can be used to provide BT clock input XTAL_IN VO Connect to crystal oscillator input VDDD P Analog Power 2.5V ~ 3.6V VDDA P Analog Power 2.5V ~ 3.6V RES12K Serial connection with a 12 kΩ resistor and connect to the ground 	24	GPIO5	I/O	GPIO 5
 XTAL_OUT I/O Connect to crystal oscillator output, can be used to provide BT clock input XTAL_IN VDDD P Analog Power 2.5V ~ 3.6V VDDA P Analog Power 2.5V ~ 3.6V RES12K Serial connection with a 12 kΩ resistor and connect to the ground 	25	UORXD	I/O	UART Rx during flash programming; GPIO 3
28 XTAL_IN I/O Connect to crystal oscillator input 29 VDDD P Analog Power 2.5V ~ 3.6V 30 VDDA P Analog Power 2.5V ~ 3.6V 31 RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	26	UOTXD	I/O	UART Tx during flash progamming; GPIO 1; SPI_CS1
 VDDD P Analog Power 2.5V ~ 3.6V VDDA P Analog Power 2.5V ~ 3.6V RES12K I Serial connection with a 12 kΩ resistor and connect to the ground 	27	XTAL_OUT	I/O	
30 VDDA P Analog Power 2.5V ~ 3.6V 31 RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	28	XTAL_IN	I/O	Connect to crystal oscillator input
RES12K I Serial connection with a 12 kΩ resistor and connect to the ground	29	VDDD	Р	Analog Power 2.5V ~ 3.6V
31 RES12K I ground	30	VDDA	Р	Analog Power 2.5V ~ 3.6V
32 EXT_RSTB I External reset signal (Low voltage level: active)	31	RES12K	I	
	32	EXT_RSTB	1	External reset signal (Low voltage level: active)

Note:

GPIO2, GPIO0, and MTDO are configurable on PCB as the 3-bit strapping register that determines the booting mode and the SDIO timing mode.



3. Functional Description

The functional diagram of ESP8266EX is shown as in Figure 3-1.

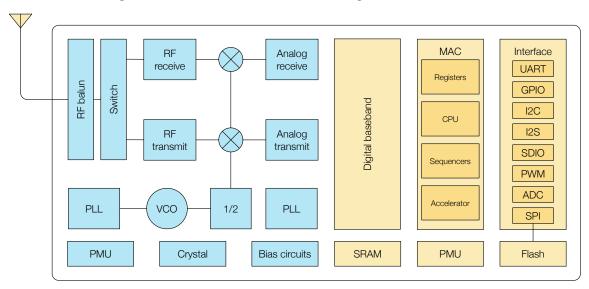


Figure 3-1. Functional Block Diagram

3.1. CPU, Memory, and Flash

3.1.1. CPU

ESP8266EX integrates Tensilica L106 32-bit micro controller (MCU) and ultra-low-power 16-bit RSIC. The CPU clock speed is 80 MHz. It can also reach a maximum value of 160 MHz. Real Time Operation System (RTOS) is enabled. Currently, only 20% of MIPS has been occupied by the Wi-Fi stack, the rest can all be used for user application programming and development. The CPU includes the interfaces as below.

- Programmable RAM/ROM interfaces (iBus), which can be connected with memory controller, and can also be used to visit flash.
- Data RAM interface (dBus), which can connected with memory controller.
- AHB interface which can be used to visit the register.

3.1.2. Memory

ESP8266EX Wi-Fi SoC integrates memory controller and memory units including SRAM and ROM. MCU can access the memory units through iBus, dBus, and AHB interfaces. All memory units can be accessed upon request, while a memory arbiter will decide the running sequence according to the time when these requests are received by the processor.

According to our current version of SDK, SRAM space available to users is assigned as below.



- RAM size < 50 kB, that is, when ESP8266EX is working under the Station mode and connects to the router, programmable space accessible in heap + data section is around 50 kB.
- There is no programmable ROM in the SoC, therefore, user program must be stored in an external SPI flash.

3.1.3. External Flash

ESP8266EX uses external SPI flash to store user programs, and supports up to 16 MB memory capacity theoretically.

The minimum flash memory of ESP8266EX is shown in Table 3-1.

Table 3-1. Minimum Flash Memory

OTA Minimum Flash Memory	
Disabled	512 kB
Enabled	1 MB

3.2. AHB and AHB Blocks

The AHB block performs as an arbiter. It controls the AHB interfaces through the MAC, SDIO (host) and CPU. Depending on the address, the AHB data requests can go into one of the two slaves.

- APB block
- Flash controller (usually for standalone applications)

Data requests to the memory controller are usually high speed requests, and requests to the APB block are usually register access.

The APB block acts as a decoder that only accesses the programmable registers within the main blocks of ESP8266EX. Depending on the address, the APB request can go to radio, SI/SPI, SDIO (host), GPIO, UART, real-time clock (RTC), MAC or digital baseband.

3.3. Clock

3.3.1. High Frequency Clock

The high frequency clock on ESP8266EX is used to drive both transmit and receive mixers. This clock is generated from internal crystal oscillator and external crystal. The crystal frequency ranges from 24 MHz to 52 MHz.

The internal calibration inside the crystal oscillator ensures that a wide range of crystals can be used, nevertheless the quality of the crystal is still a factor to consider to have reasonable phase noise and good Wi-Fi sensitivity. Refer to Table 3-2 to measure the frequency offset.



Table 3-2. High Frequency Clock Specifications

Parameter	Symbol	Min	Max	Unit
Frequency	FXO	24	52	MHz
Loading capacitance	CL	-	32	pF
Motional capacitance	CM	2	5	pF
Series resistance	RS	0	65	Ω
Frequency tolerance	ΔΕΧΟ	-15	15	ppm
Frequency vs temperature (-25°C ~ 75°C)	ΔFXO,Temp	-15	15	ppm

3.3.2. External Clock Requirements

An externally generated clock is available with the frequency ranging from 24 MHz to 52 MHz. The following characteristics are expected to achieve good performance of radio.

Table 3-3. External Clock Reference

Parameter	Symbol	Min	Max	Unit
Clock amplitude	VXO	0.8	1.5	Vpp
External clock accuracy	ΔFXO,EXT	-15	15	ppm
Phase noise @1-kHz offset, 40-MHz clock	-	-	-120	dBc/Hz
Phase noise @10-kHz offset, 40-MHz clock	-	-	-130	dBc/Hz
Phase noise @100-kHz offset, 40-MHz clock	-	-	-138	dBc/Hz

3.4. Radio

ESP8266EX radio consists of the following blocks.

- 2.4 GHz receiver
- 2.4 GHz transmitter
- High speed clock generators and crystal oscillator
- Real time clock
- Bias and regulators
- Power management

3.4.1. Channel Frequencies

The RF transceiver supports the following channels according to IEEE802.11b/g/n standards.

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Table 3-4. Frequency Channel

Channel No.	Frequency (MHz)	Channel No.	Frequency (MHz)
1	2412	8	2447
2	2417	9	2452
3	2422	10	2457
4	2427	11	2462
5	2432	12	2467
6	2437	13	2472
7	2442	14	2484

3.4.2. 2.4 GHz Receiver

The 2.4 GHz receiver down-converts the RF signals to quadrature baseband signals and converts them to the digital domain with 2 high resolution high speed ADCs. To adapt to varying signal channel conditions, RF filters, automatic gain control (AGC), DC offset cancelation circuits and baseband filters are integrated within ESP8266EX.

3.4.3. 2.4 GHz Transmitter

The 2.4 GHz transmitter up-converts the quadrature baseband signals to 2.4 GHz, and drives the antenna with a high-power CMOS power amplifier. The function of digital calibration further improves the linearity of the power amplifier, enabling a state of art performance of delivering +19.5 dBm average power for 802.11b transmission and +16 dBm for 802.11n transmission.

Additional calibrations are integrated to offset any imperfections of the radio, such as:

- Carrier leakage
- I/Q phase matching
- Baseband nonlinearities

These built-in calibration functions reduce the product test time and make the test equipment unnecessary.

3.4.4. Clock Generator

The clock generator generates quadrature 2.4 GHz clock signals for the receiver and transmitter. All components of the clock generator are integrated on the chip, including all inductors, varactors, filters, regulators and dividers.

The clock generator has built-in calibration and self test circuits. Quadrature clock phases and phase noise are optimized on-chip with patented calibration algorithms to ensure the best performance of the receiver and transmitter.

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3.5. Wi-Fi

ESP8266EX implements TCP/IP, the full 802.11 b/g/n/e/i WLAN MAC protocol and Wi-Fi Direct specification. It supports not only basic service set (BSS) operations under the distributed control function (DCF) but also P2P group operation compliant with the latest Wi-Fi P2P protocol. Low level protocol functions are handled automatically by ESP8266EX.

- RTS/CTS
- acknowledgement
- fragmentation and defragmentation
- aggregation
- frame encapsulation (802.11h/RFC 1042)
- automatic beacon monitoring / scanning, and
- P2P Wi-Fi direct

Like P2P discovery procedure, passive or active scanning is performed autonomously once initiated by the appropriate command. Power management is handled with minimum interaction with host to minimize active duty period.

3.6. Power Management

ESP8266EX is designed with advanced power management technologies and intended for mobile devices, wearable electronics and the Internet of Things applications.

The low-power architecture operates in 3 modes: active mode, sleep mode and Deepsleep mode. ESP8266EX consumes about 20 μ A of power in Deep-sleep mode (with RTC clock still running) and less than 1.0 mA (DTIM=3) or less than 0.6 mA (DTIM=10) to stay connected to the access point.



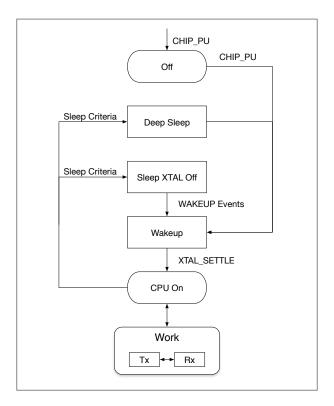


Figure 3-2. Power Management

- Off: CHIP_PU pin is low. The RTC is disabled. All registers are cleared.
- **Deep-sleep**: Only RTC is powered on the rest of the chip is powered off. Recovery memory of RTC can save basic Wi-Fi connection information.
- Sleep: Only the RTC is operating. The crystal oscillator is disabled. Any wake-up events (MAC, host, RTC timer, external interrupts) will put the chip into the wakeup mode.
- **Wakeup**: In this state, the system switches from the sleep states to the PWR mode. The crystal oscillator and PLLs are enabled.
- On: The high speed clock is able to operate and sent to each block enabled by the clock control register. Lower level clock gating is implemented at the block level, including the CPU, which can be gated off using the WAITI instruction while the system is on.



4.

Peripheral Interface

4.1. General Purpose Input/Output Interface (GPIO)

ESP8266EX has 17 GPIO pins which can be assigned to various functions by programming the appropriate registers.

Each GPIO can be configured with internal pull-up or pull-down, or set to high impedance, and when configured as an input, the data are stored in software registers; the input can also be set to edge-trigger or level trigger CPU interrupts. In short, the IO pads are bi-directional, non-inverting and tristate, which includes input and output buffer with tristate control inputs.

These pins can be multiplexed with other functions such as I2C, I2S, UART, PWM, IR Remote Control, LED Light and Button etc.

For low power operations, the GPIOs can also be set to hold their state. For instance, when the chip is powered down, all output enable signals can be set to hold low.

Optional hold functionality can be built into the IO if requested. When the IO is not driven by the internal or external circuitry, the hold functionality can be used to hold the state to the last used state. The hold functionality introduces some positive feedback into the pad. Hence, the external driver that drives the pad must be stronger than the positive feedback. The required drive strength is small — in the range of $5 \,\mu\text{A}$ to pull apart the latch.

4.2. Secure Digital Input/Output Interface (SDIO)

ESP8266EX has one Slave SDIO, the definitions of which are described as Table 4-1.

Pin Name Pin Num 10 **Function Name** SDIO_CLK 21 106 SDIO_CLK SDIO DATAO 22 107 SDIO DATAO SDIO DATA1 23 **IO8** SDIO_DATA1 SDIO_DATA_2 18 109 SDIO_DATA_2 SDIO_DATA_3 19 1010 SDIO_DATA_3 SDIO_CMD 20 1011 SDIO_CMD

Table 4-1. Pin Definitions of SDIOs

Note:

4-bit 25 MHz SDIO v1.1 and 4-bit 50 MHz SDIO v2.0 are supported.



4.3. Serial Peripheral Interface (SPI/HSPI)

ESP8266EX has three SPIs.

- One general Slave/Master SPI
- One Slave SDIO/SPI
- One general Slave/Master HSPI

Functions of all these pins can be implemented via hardware. The pin definitions are described as below.

4.3.1. General SPI (Master/Slave)

Table 4-2. Pin Definitions of SPIs

Pin Name	Pin Num	Ю	Function Name
SDIO_CLK	21	106	SPICLK
SDIO_DATA0	22	107	SPIQ/MISO
SDIO_DATA1	23	IO8	SPID/MOSI
SDIO_DATA_2	18	109	SPIHD
SDIO_DATA_3	19	IO10	SPIWP
UOTXD	26	IO1	SPICS1
GPI00	15	IO0	SPICS2



SPI mode can be implemented via software programming. The clock frequency is 80 MHz at maximum.

4.3.2. HSPI (Slave)

Table 4-3. Pin Definitions of HSPI (Slave)

Pin Name	Pin Num	IO	Function Name
MTMS	9	IO14	HSPICLK
MTDI	10	IO12	HSPIQ/MISO
MTCK	12	IO13	HSPID/MOSI
MTDO	13	IO15	HPSICS

4.4. I2C Interface

ESP8266EX has one I2C used to connect with micro-controller and other peripheral equipments such as sensors. The pin definition of I2C is as below.



Table 4-4. Pin Definitions of I2C

Pin Name	Pin Num	Ю	Function Name
MTMS	9	IO14	I2C_SCL
GPIO2	14	IO2	I2C_SDA

Both I2C Master and I2C Slave are supported. I2C interface functionality can be realized via software programming, and the clock frequency is 100 kHz at a maximum. It should be noted that I2C clock frequency should be higher than the slowest clock frequency of the slave device.

4.5. I2S Interface

ESP8266EX has one I2S data input interface and one I2S data output interface. I2S interfaces are mainly used in applications such as data collection, processing, and transmission of audio data, as well as the input and output of serial data. For example, LED lights (WS2812 series) are supported. The pin definition of I2S is shown in Table 4-5. I2S functionality can be enabled via software programming by using multiplexed GPIOs, and linked list DMA is supported.

Table 4-5. Pin Definitions of I2S

I2S Data Input					
Pin Name	Pin Num	Function Name			
MTDI	10	IO12	I2SI_DATA		
MTCK	12	IO13	I2SI_BCK		
MTMS	9	IO14	I2SI_WS		
MTDO	13	IO15	I2SO_BCK		
UORXD	25	IO3	I2SO_DATA		
GPIO2	14	102	12SO_WS		

4.6. Universal Asynchronous Receiver Transmitter (UART)

ESP8266EX has two UART interfaces UART0 and UART, the definitions are shown in Table 4-6.

Table 4-6. Pin Definitions of UART

Pin Type	Pin Name	Pin Num	Ю	Function Name	
	U0RXD	25	IO3	UORXD	
UARTO	UOTXD	26	IO1	U0TXD	
OAITIO	MTDO	13	IO15	UORTS	

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Pin Type	Pin Name	Pin Num	Ю	Function Name
	MTCK	12	IO13	UOCTS
LIADT4	GPIO2	14	IO2	U1TXD
UART1	SD_D1	23	IO8	U1RXD

Data transfers to/from UART interfaces can be implemented via hardware. The data transmission speed via UART interfaces reaches 115200 x 40 (4.5 Mbps).

UARTO can be used for communication. It supports fluid control. Since UART1 features only data transmit signal (Tx), it is usually used for printing log.

Note:

By default, UARTO outputs some printed information when the device is powered on and booting up. The baud rate of the printed information is relevant to the frequency of the external crystal oscillator. If the frequency of the crystal oscillator is 40 MHz, then the baud rate for printing is 115200; if the frequency of the crystal oscillator is 26 MHz, then the baud rate for printing is 74880. If the printed information exerts any influence on the functionality of the device, it is suggested to block the printing during the power-on period by changing (UOTXD, UORXD) to (MTDO, MTCK).

4.7. Pulse-Width Modulation (PWM)

ESP8266EX has four PWM output interfaces. They can be extended by users themselves. The pin definitions of the PWM interfaces are defined as below.

Pin Name	Pin Num	Ю	Function Name
MTDI	10	IO12	PWM0
MTDO	13	IO15	PWM1
MTMS	9	IO14	PWM2
GPIO4	16	IO4	PWM3

Table 4-7. Pin Definitions of PWM

The functionality of PWM interfaces can be implemented via software programming. For example, in the LED smart light demo, the function of PWM is realized by interruption of the timer, the minimum resolution reaches as high as 44 ns. PWM frequency range is adjustable from $1000 \, \mu s$ to $10000 \, \mu s$, i.e., between $100 \, Hz$ and $1 \, kHz$. When the PWM frequency is $1 \, kHz$, the duty ratio will be 1/22727, and a resolution of over $14 \, bits$ will be achieved at $1 \, kHz$ refresh rate.

4.8. IR Remote Control

One Infrared remote control interface is defined as below.



Table 4-8. Pin Definitions of IR Remote Control

Pin Name	Pin Num	Num IO Function Name	
MTMS	9	IO14	IR Tx
GPIO5	24	IO 5	IR Rx

The functionality of Infrared remote control interface can be implemented via software programming. NEC coding, modulation, and demodulation are used by this interface. The frequency of modulated carrier signal is 38 kHz, while the duty ratio of the square wave is 1/3. The transmission range is around 1m which is determined by two factors: one is the maximum value of rated current, the other is internal current-limiting resistance value in the infrared receiver. The larger the resistance value, the lower the current, so is the power, and vice versa. The transmission angle is between 15° and 30° which is determined by the radiation direction of the infrared receiver.

4.9. ADC (Analog-to-Digital Converter)

ESP8266EX is embedded with a 10-bit precision SARADC. TOUT (Pin6) is defined as below:

Table 4-9. Pin Definition of ADC

Pin Name	Pin Num	Function Name
TOUT	6	ADC Interface

The following two functions can be implemented using ADC (Pin 6). However, they cannot be implemented at the same time.

• Test the power supply voltage of VDD3P3 (Pin 3 and Pin 4).

Hardware Design	TOUT must be floating.
RF Initialization Parameter	The 107th byte of <i>esp_init_data_default.bin</i> (0 ~ 127 bytes), vdd33_const must be set to 0xFF.
RF Calibration Process	Optimize the RF circuit conditions based on the testing results of VDD3P3 (Pin 3 and Pin 4).
User Programming	Use system_get_vdd33 instead of system_adc_read.

• Test the input voltage of TOUT (Pin 6).

Hardware Design	The input voltage range is 0 to 1.0V when TOUT is connected to external circuit.
RF Initialization Parameter	The value of the 107th byte of <i>esp_init_data_default.bin</i> (0 ~ 127 bytes), vdd33_const must be set to the real power supply voltage of Pin 3 and Pin 4. The working power voltage range of ESP8266EX is between 1.8V and 3.6V, while the unit of vdd33_const is 0.1V, therefore, the effective value range of vdd33_const is 18 to 36.

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RF Calibration Process	Optimize the RF circuit conditions based on the value of $vdd33_const$. The permissible error is $\pm 0.2V$.
User Programming	Use system_adc_read instead of system_get_vdd33.

Notes:

esp_init_data_default.bin is provided in SDK package which contains RF initialization parameters (0 ~ 127 bytes).

You can define the 107th byte in esp_init_data_default.bin to vdd33_const as below.

- If vdd33_const = 0xff, the power voltage of Pin 3 and Pin 4 will be tested by the internal self-calibration process of ESP8266EX itself. RF circuit conditions should be optimized according to the testing results.
- If 18 =< vdd33_const =< 36, ESP8266EX RF Calibration and optimization process is implemented via (vdd33_const/10).
- If vdd33_const < 18 or 36 < vdd33_const < 255, ESP8266EX RF Calibration and optimization process is implemented via the default value 2.5V.

4.10. LED Light and Button

ESP8266EX features 17 GPIOs, all of which can be assigned to support various functions of LED lights and buttons. Definitions of some GPIOs that are assigned with certain functions in demo application design are shown as below:

Table 4-10. Pin Definition of LED and Button

Pin Name	Pin Num	Ю	Function Name
MTCK	12	IO 13	Button (Reset)
GPI00	15	IO 0	Wi-Fi Light
MTDI	10	IO 12	Link Light

Altogether three interfaces have been defined, one is for the button, while the other two are for LED light. Generally, MTCK is used for controlling the reset button; GPIO0 is used as an signal to indicate the Wi-Fi working state; MTDI is used as a signal light to indicate communication status between the device and the server.

Note:

Most interfaces described in this chapter can be multiplexed. Pin definitions that can be defined is not limited to the ones herein mentioned; you can customize the functions of the pins according to your specific application scenarios via software programming and hardware design.

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2

0.5

ΚV

KV



5. Electrical Specifications

5.1. Electrical Characteristics

Parameters Conditions Min Typical Max Unit Storage Temperature Range -40 Normal 125 $^{\circ}C$ IPC/JEDEC J-Maximum Soldering Temperature 260 $^{\circ}\text{C}$ STD-020 Working Voltage Value \bigvee 2.5 3.3 3.6 $0.25V_{10}/$ V_{II}/V_{IH} -0.3/0.75V_{IO} 3.6 1/0 Vol/Voh $0.1V_{IO}/N$ $N/0.8V_{IO}$ 12 I_{MAX} mΑ

Table 5-1. Electrical Characteristics

5.2. Power Consumption

Electrostatic Discharge (HBM)

Electrostatic Discharge (CDM)

Unless otherwise specified, the power consumption measurements are taken with a 3.0V supply at 25°C of ambient temperature. All transmitters' measurements are based on a 50% duty cycle.

TAMB=25°C

TAMB=25°C

Table 5-2. Power Consumption

Parameters	Min	Typical	Max	Unit
Tx802.11b, CCK 11Mbps, P OUT=+17dBm	-	170	-	mA
Tx 802.11g, OFDM 54Mbps, P OUT =+15dBm	-	140	-	mA
Tx 802.11n, MCS7, P OUT =+13dBm	-	120	-	mA
Rx 802.11b, 1024 bytes packet length , -80dBm	-	50	-	mA
Rx 802.11g, 1024 bytes packet length, -70dBm	-	56	-	mA
Rx 802.11n, 1024 bytes packet length, -65dBm	-	56	-	mA
Modem-sleep ^①	-	15	-	mA
Light-sleep ²	-	0.9	-	mA
Deep-sleep [®]	-	20	-	μΑ
Power Off	-	0.5	-	μΑ

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Notes:

- ① Modem-sleep mode is used in the applications that require the CPU to be working, as in PWM or I2S applications. According to 802.11 standards (like U-APSD), it shuts down the Wi-Fi Modem circuit while maintaining a Wi-Fi connection with no data transmission to optimize power consumption. E.g. in DTIM3, maintaining a sleep of 300 ms with a wakeup of 3 ms cycle to receive AP's Beacon packages at interval requires about 15 mA current.
- ② During Light-sleep mode, the CPU may be suspended in applications like Wi-Fi switch. Without data transmission, the Wi-Fi Modern circuit can be turned off and CPU suspended to save power consumption according to the 802.11 standards (U-APSD). E.g. in DTIM3, maintaining a sleep of 300 ms with a wakeup of 3ms to receive AP's Beacon packages at interval requires about 0.9 mA current.
- 3 During Deep-sleep mode, Wi-Fi is turned off. For applications with long time lags between data transmission, e.g. a temperature sensor that detects the temperature every 100s, sleeps for 300s and wakes up to connect to the AP (taking about 0.3 ~ 1s), the overall average current is less than 1mA. The current of 20 μA is acquired at the voltage of 2.5V.

5.3. Wi-Fi Radio Characteristics

The following data are from tests conducted at room temperature, with a 3.3V power supply.

Table 5-3. Wi-Fi Radio Characteristics

Parameters	Min	Typical	Max	Unit
Input frequency	2412	-	2484	MHz
Output impedance	-	39+j6	-	Ω
Input reflection	-	-	-10	dB
Output power of PA for 72.2 Mbps	15.5	16.5	17.5	dBm
Output power of PA for 11b mode	19.5	20.5	21.5	dBm
Sensitivity				
DSSS, 1 Mbps	-	-98	-	dBm
CCK, 11 Mbps	-	-91	-	dBm
6 Mbps (1/2 BPSK)	-	-93	-	dBm
54 Mbps (3/4 64-QAM)	-	-75	-	dBm
HT20, MCS7 (65 Mbps, 72.2 Mbps)	-	-72	-	dBm
Adjacent Channel Rejection				
OFDM, 6 Mbps	-	37	-	dB
OFDM, 54 Mbps	-	21	-	dB
HT20, MCS0	-	37	-	dB
HT20, MCS7	-	20	-	dB

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6.

Package Information

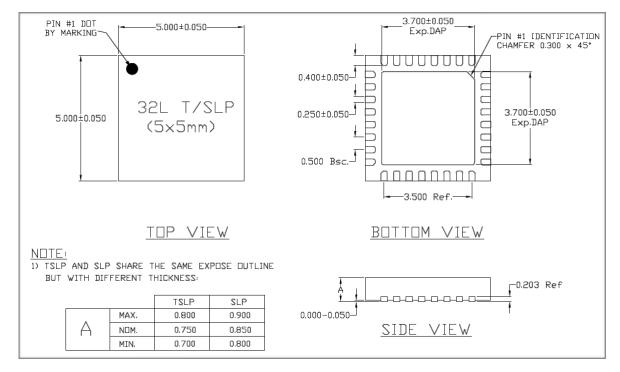


Figure 6-1. ESP8266EX Package



L

Appendix - Pin List

For detailed pin information, please see **ESP8266 Pin List**.

- Digital Die Pin List
- Buffer Sheet
- Register List
- Strapping List

Notes:

- INST_NAME refers to the IO_MUX REGISTER defined in **eagle_soc.h**, for example MTDI_U refers to PERIPHS_IO_MUX_MTDI_U.
- Net Name refers to the pin name in schematic.
- Function refers to the multifunction of each pin pad.
- Function number 1 ~ 5 correspond to FUNCTION 0 ~ 4 in SDK. For example, set MTDI to GPIO12 as follows.
 - #define FUNC_GPI012 3 //defined in eagle_soc.h
 - PIN_FUNC_SELECT(PERIPHS_IO_MUX_MTDI_U,FUNC_GPI012)



II.

Appendix - Learning Resources

II.1. Must-Read Documents

• ESP8266 Quick Start Guide

Description: This document is a quick user guide to getting started with ESP8266. It includes an introduction to the ESP-LAUNCHER, instructions on how to download firmware to the board and run it, how to compile the AT application, as well as the structure and debugging method of RTOS SDK. Basic documentation and other related resources for the ESP8266 are also provided.

ESP8266 SDK Getting Started Guide

Description: This document takes ESP-LAUNCHER and ESP-WROOM-02 as examples of how to use the ESP8266 SDK. The contents include preparations before compilation, SDK compilation and firmware download.

• ESP8266 Pin List

Description: This link directs you to a list containing the type and function of every ESP8266 pin.

• ESP8266 System Description

Description: This document provides a technical description of the ESP8266 series of products, including ESP8266EX, ESP-LAUNCHER and ESP-WROOM.

• ESP8266 Hardware Matching Guide

Description: This document introduces the frequency offset tuning and antenna impedance matching for ESP8266 in order to achieve optimal RF performance.

• ESP8266 Technical Reference

Description: This document provides an introduction to the interfaces integrated on ESP8266. Functional overview, parameter configuration, function description, application demos and other pieces of information are included.

• ESP8266 Hardware Resources

Description: This zip package includes manufacturing BOMs, schematics and PCB layouts of ESP8266 boards and modules.

FAQ

II.2. Must-Have Resources

ESP8266 SDKs



Description: This webpage provides links both to the latest version of the ESP8266 SDK and the older ones.

• ESP8266 Tools

Description: This webpage provides links to both the ESP8266 flash download tools and the ESP8266 performance evaluation tools.

- ESP8266 Apps
- ESP8266 Certification and Test Guide
- ESP8266 BBS
- ESP8266 Resources



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